



N-Channel Reduced Q_g, Fast Switching MOSFET

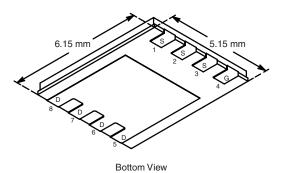
| PRODUCT SUMMARY | | | | | | |
|---------------------|--------------------------------------|--|------|--|--|--|
| V _{DS} (V) | $R_{DS(on)}(\Omega)$ | I _D (A) Q _g (Typ | | | | |
| 30 | 0.007 at V _{GS} = 10 V | 19 | 11.5 | | | |
| | 0.0095 at $V_{GS} = 4.5 \text{ V}$ | 17 | 11.5 | | | |

FEATURES

- · Halogen-free available
- TrenchFET® Gen II Power MOSFET
- · PWM Optimized for High Efficiency
- New Low Thermal Resistance PowerPAK[®]
 Package with Low 1.07 mm Profile
- 100 % R_g Tested

RoHS COMPLIANT

PowerPAK SO-8

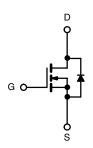


Ordering Information: Si7386DP-T1-E3 (Lead (Pb)-free)

Si7386DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

APPLICATIONS

• DC/DC Conversion for PC



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS T | ₄ = 25 °C, unle | ss otherwise n | oted | | | |
|---|----------------------------|-----------------------------------|--------------|------|----|--|
| Parameter | Symbol | 10 s | Steady State | Unit | | |
| Drain-Source Voltage | | V _{DS} | 30 | | V | |
| Gate-Source Voltage | | V _{GS} | ± 20 | | | |
| Continuous Dusin Comment /T 450 000 | T _A = 25 °C | - I _D | 19 | 12 | | |
| Continuous Drain Current (T _J = 150 °C) ^a | T _A = 70 °C | | 16 | 9 | | |
| Pulsed Drain Current | | I _{DM} | ± 50 | | Α | |
| Continuous Source Current (Diode Conduction) ^a | | I _S | 4.1 | 1.5 | | |
| Avalanche Current | | I _{AS} | 25 | | | |
| Single Pulse Avalanche Energy L = 0.1 mH | | E _{AS} | 32 | | mJ | |
| Mariana Dana Biraira Kad | T _A = 25 °C | P _D | 5 | 1.8 | W | |
| Maximum Power Dissipation ^a | T _A = 70 °C | LD. | 3.2 | 1.1 | VV | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | | °C | |
| Soldering Recommendations (Peak Temperature) ^{b, c} | | | 260 | | °C | |

| THERMAL RESISTANCE RATINGS | | | | | | |
|---|--------------|-------------------|---------|------|------|--|
| Parameter | Symbol | Typical | Maximum | Unit | | |
| Marian and Luncking to Architect (MOCEFT) | t ≤ 10 s | R _{thJA} | 21 | 25 | °C/W | |
| Maximum Junction-to-Ambient (MOSFET) ^a | Steady State | ' 'thJA | 56 | 70 | | |
| Maximum Junction-to-Case (Drain) | Steady State | R _{thJC} | 2.4 | 3.0 | | |

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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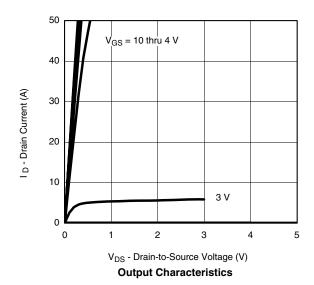
| MOSFET SPECIFICATIONS T _J = 25 °C, unless otherwise noted | | | | | | | |
|--|---------------------|---|------|--------|-------|------|--|
| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit | |
| Static | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 1.5 | 2.0 | 2.5 | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | | ± 100 | nA | |
| Zava Cata Valtaga Dvain Current | 1 | V _{DS} = 30 V, V _{GS} = 0 V | | | 1 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} = 30 V, V_{GS} = 0 V, T_{J} = 70 °C | | | 15 | μΑ | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$ | 40 | | | Α | |
| 5 1 2 2 2 2 1 2 2 | В | V _{GS} = 10 V, I _D = 19 A | | 0.0058 | 0.007 | Ω | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 4.5 V, I _D = 17 A 0.0078 | | 0.0095 | 1 22 | | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = 15 V, I _D = 19 A | | 50 | | S | |
| Diode Forward Voltage ^a | V_{SD} | I _S = 4.1 A, V _{GS} = 0 V | | 0.78 | 1.1 | V | |
| Dynamic ^b | | | | | | | |
| Total Gate Charge | Q_g | | | 11.5 | 18 | | |
| Gate-Source Charge | Q_{gs} | $V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 19 \text{ A}$ | | 5.8 | | nC | |
| Gate-Drain Charge | Q_{gd} | | | 3.0 | | | |
| Gate Resistance | R_{g} | | 0.8 | 1.7 | 2.5 | Ω | |
| Turn-On Delay Time | t _{d(on)} | | | 12 | 18 | | |
| Rise Time | t _r | V_{DD} = 15 V, R_L = 15 Ω | | 9 | 14 | | |
| Turn-Off Delay Time | t _{d(off)} | $I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω | | 35 | 53 | ns | |
| Fall Time | t _f | | | 10 | 15 | | |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = 2.8 A, di/dt = 100 A/μs | | 25 | 50 | | |

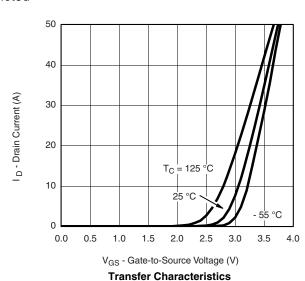
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



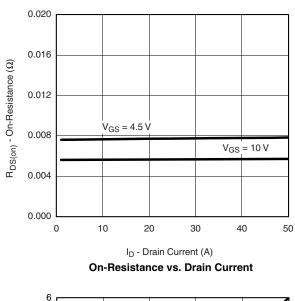


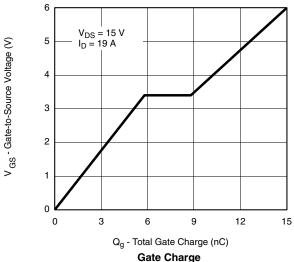


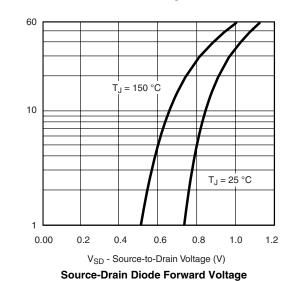


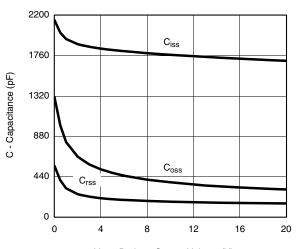


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

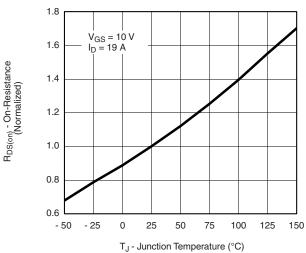




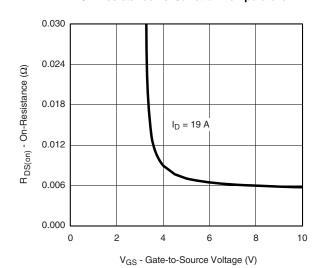




V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature



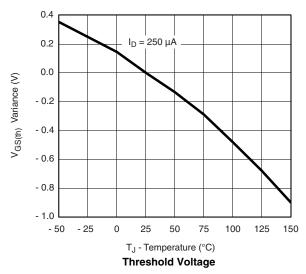
On-Resistance vs. Gate-to-Source Voltage

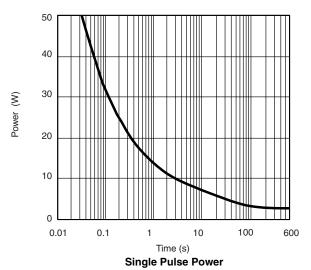
Is - Source Current (A)

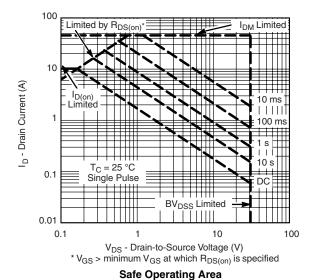
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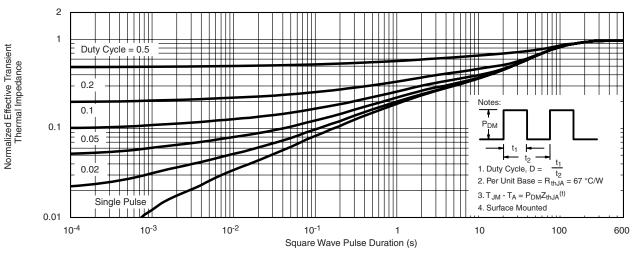
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





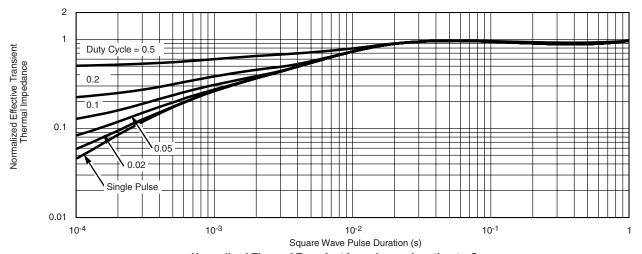




Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

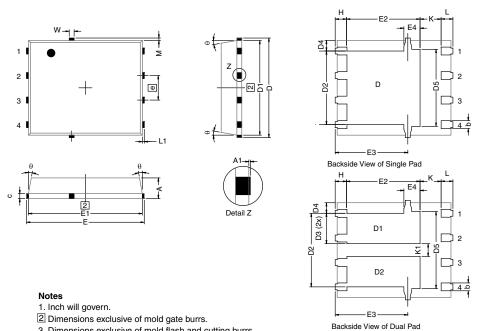
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Document Number: 73108 S-80439-Rev. C, 03-Mar-08



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



| 3. Dimensions exclusive of mold flash and cutting burrs. | | | | | | | |
|--|------|-------------|------|--------|-------|-------|--|
| | | MILLIMETERS | | INCHES | | | |
| DIM. | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | |
| A | 0.97 | 1.04 | 1.12 | 0.038 | 0.041 | 0.044 | |
| A1 | | - | 0.05 | 0 | - | 0.002 | |
| b | 0.33 | 0.41 | 0.51 | 0.013 | 0.016 | 0.020 | |
| С | 0.23 | 0.28 | 0.33 | 0.009 | 0.011 | 0.013 | |
| D | 5.05 | 5.15 | 5.26 | 0.199 | 0.203 | 0.207 | |
| | 4.00 | 4.00 | F 00 | 0.400 | 0.400 | 0.407 | |

| Α | 0.97 | 1.04 | 1.12 | 0.038 | 0.041 | 0.044 | |
|--------------------------|------------|-----------|------|------------|-------------|-------|--|
| A1 | | - | 0.05 | 0 | - | 0.002 | |
| b | 0.33 | 0.41 | 0.51 | 0.013 | 0.016 | 0.020 | |
| С | 0.23 | 0.28 | 0.33 | 0.009 | 0.011 | 0.013 | |
| D | 5.05 | 5.15 | 5.26 | 0.199 | 0.203 | 0.207 | |
| D1 | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 | |
| D2 | 3.56 | 3.76 | 3.91 | 0.140 | 0.148 | 0.154 | |
| D3 | 1.32 | 1.50 | 1.68 | 0.052 | 0.059 | 0.066 | |
| D4 | | 0.57 typ. | | | 0.0225 typ. | | |
| D5 | | 3.98 typ. | | | 0.157 typ. | | |
| E | 6.05 | 6.15 | 6.25 | 0.238 | 0.242 | 0.246 | |
| E1 | 5.79 | 5.89 | 5.99 | 0.228 | 0.232 | 0.236 | |
| E2 (for AL product) | 3.30 | 3.48 | 3.66 | 0.130 | 0.137 | 0.144 | |
| E2 (for other product) | 3.48 | 3.66 | 3.84 | 0.137 | 0.144 | 0.151 | |
| E3 | 3.68 | 3.78 | 3.91 | 0.145 | 0.149 | 0.154 | |
| E4 (for AL product) | | 0.58 typ. | | 0.023 typ. | | | |
| E4 (for other product) | | 0.75 typ. | | 0.030 typ. | | | |
| е | | 1.27 BSC | | 0.050 BSC | | | |
| K (for AL product) | | 1.45 typ. | | 0.057 typ. | | | |
| K (for other product) | | 1.27 typ. | | 0.050 typ. | | | |
| K1 | 0.56 | - | = | 0.022 | - | = | |
| Н | 0.51 | 0.61 | 0.71 | 0.020 | 0.024 | 0.028 | |
| L | 0.51 | 0.61 | 0.71 | 0.020 | 0.024 | 0.028 | |
| L1 | 0.06 | 0.13 | 0.20 | 0.002 | 0.005 | 0.008 | |
| θ | 0° | - | 12° | 0° | - | 12° | |
| W | 0.15 | 0.25 | 0.36 | 0.006 | 0.010 | 0.014 | |
| M | 0.125 typ. | | | 0.005 typ. | | | |
| ECN: C13-0702-Rev. K, 20 |)-May-13 | | | • | | | |

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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